

TOSHIBA INTEGRATED IGBT MODULE SILICON N CHANNEL IGBT

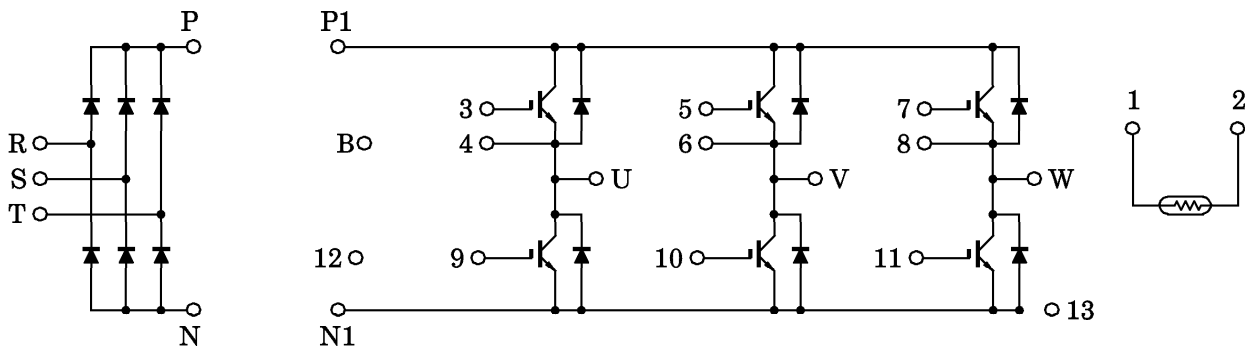
MIG30J806H, MIG30J806HA

HIGH POWER SWITCHING APPLICATIONS

MOTOR CONTROL APPLICATIONS

- Integrates Inverter, Converter Power Circuits and Thermistor in One Package.
- Output (Inverter Stage) : 3 ϕ 30A / 600V IGBT
- Input (Converter Stage) : 3 ϕ 30A / 800V Silicon Rectifier
- The Electrodes are Isolated from Case.
- Outline
 - MIG30J806H : 2-108E5A
 - MIG30J806HA : 2-108E6A
- Weight : 190g

EQUIVALENT CIRCUIT



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MAXIMUM RATINGS (Ta = 25°C)

STAGE	CHARACTERISTIC	SYMBOL	RATING	UNIT	
Inverter	Collector-Emitter Voltage	V _{CES}	600	V	
	Gate-Emitter Voltage	V _{GES}	±20	V	
	Collector Current	DC	I _C	35 / 30	A
		1ms	I _{CP}	70 / 60	A
	Forward Current	DC	I _F	30	A
		1ms	I _{FM}	60	A
Collector Power Dissipation (T _c = 25°C)		P _C	125	W	
Converter	Repetitive Peak Reverse Voltage	V _{RRM}	800	V	
	Average Output Rectified Current	I _O	30	A	
	Peak One Cycle Surge Forward Current (50Hz, Non-Repetitive)	I _{FSM}	400	A	
Module	Junction Temperature	T _j	150	°C	
	Storage Temperature Range	T _{stg}	-40~125	°C	
	Isolation Voltage	V _{Isol}	2500 (AC 1 minute)	V	
	Screw Torque	—	6	N·m	

(25°C / 40°C)
(25°C / 40°C)

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

a. Inverter stage

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Gate Leakage Current		I_{GES}	$V_{GE} = \pm 20V, V_{CE} = 0$	—	—	± 500	nA
Collector Cut-Off Current		I_{CES}	$V_{CE} = 600V, V_{GE} = 0$	—	—	1.0	mA
Gate-Emitter Cut-Off Voltage		$V_{GE} (off)$	$I_C = 3mA, V_{CE} = 5V$	5.0	—	8.0	V
Collector-Emitter Saturation Voltage		$V_{CE} (sat)$	$I_C = 30A$	—	2.1	2.7	V
			$V_{GE} = 15V$		2.2	2.8	
Input Capacitance		C_{ies}	$V_{CE} = 10V, V_{GE} = 0, f = 1MHz$	—	—	—	pF
Switching Time	Rise Time	t_r	$V_{CC} = 300V$ $I_C = 30A$ $V_{GE} = \pm 15V$ $R_G = 43\Omega$ (Note 1)	—	0.10	0.20	μs
	Turn-On Time	t_{on}		—	0.25	0.50	
	Fall Time	t_f		—	0.15	0.30	
	Turn-Off Time	t_{off}		—	0.50	0.80	
Forward Voltage		V_F	$I_F = 30A, V_{GE} = 0$	—	2.0	2.8	V
Reverse Recovery Time		t_{rr}	$I_F = 30A, V_{GE} = -10V$ $di/dt = 100A/\mu s$	—	0.08	0.15	μs
Thermal Resistance		$R_{th(j-c)}$	Transistor	—	—	1.0	$^{\circ}C/W$
			Diode	—	—	2.6	

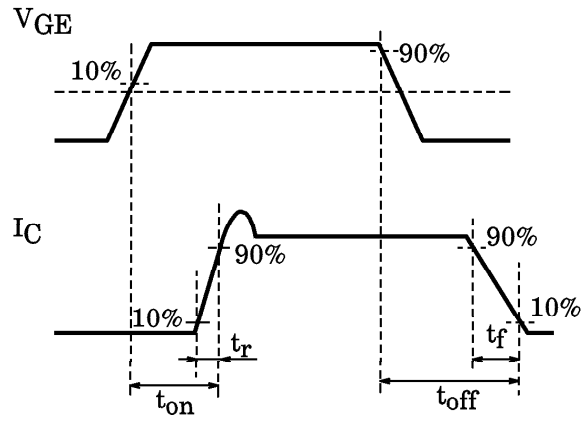
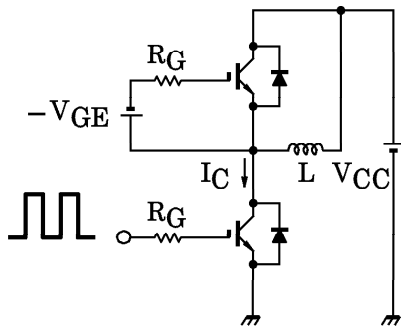
b. Converter stage

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Repetitive Peak Reverse Current		I_{RRM}	$V_{RRM} = 800V$	—	—	50	μA
Peak Forward Voltage		V_{FM}	$I_{FM} = 30A$	—	1.05	1.20	V
Peak One Cycle Surge Forward Current		I_{FSM}	50Hz sine-half-wave	400	—	—	A
Thermal Resistance		$R_{th(j-c)}$	—	—	—	1.56	$^{\circ}C/W$

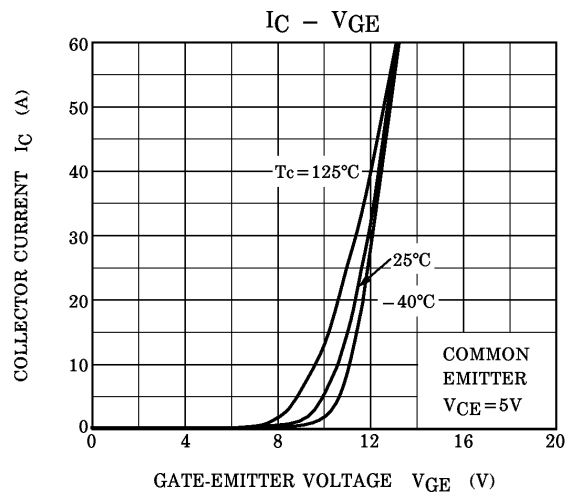
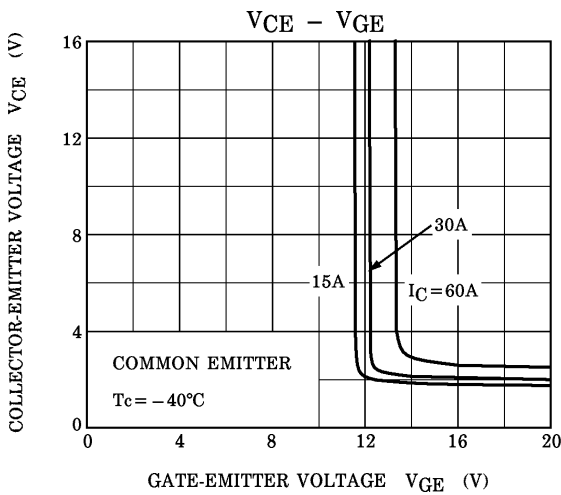
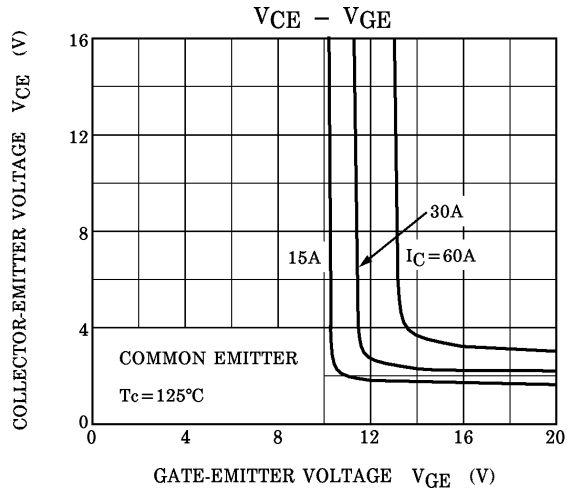
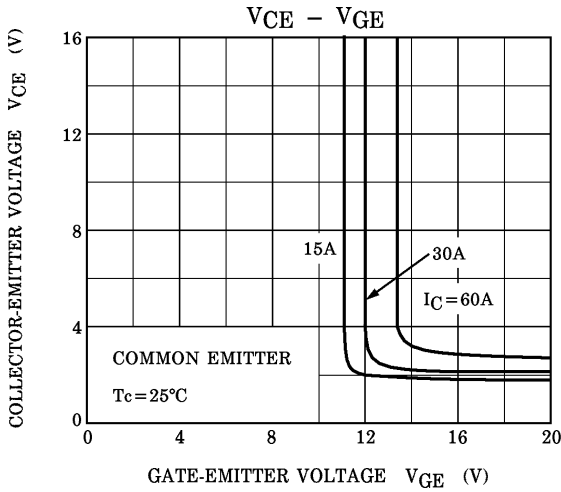
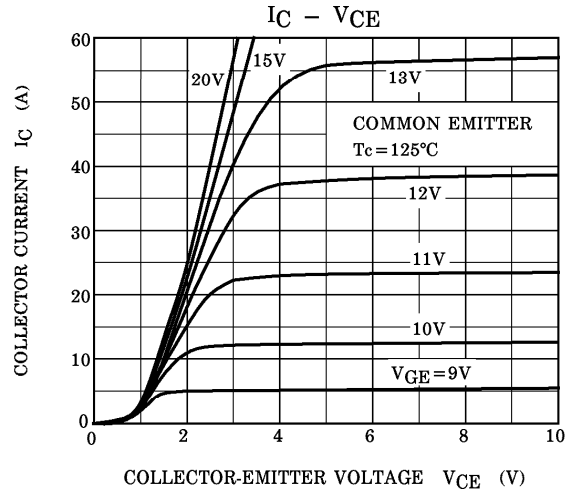
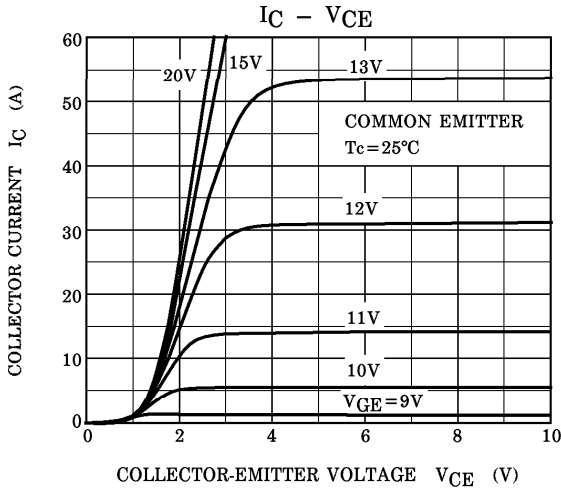
c. Thermistor

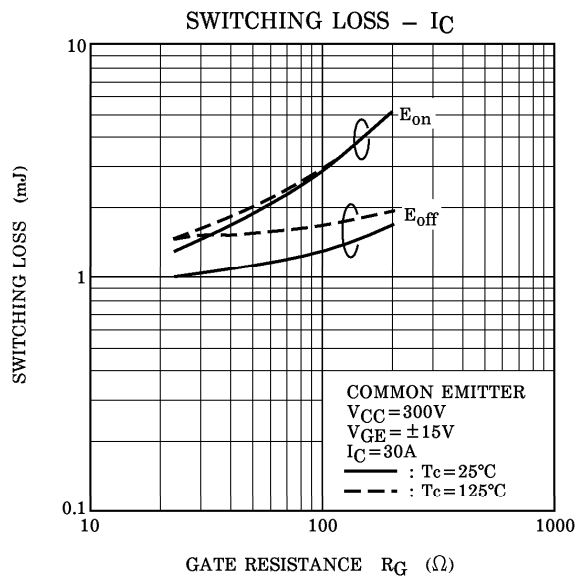
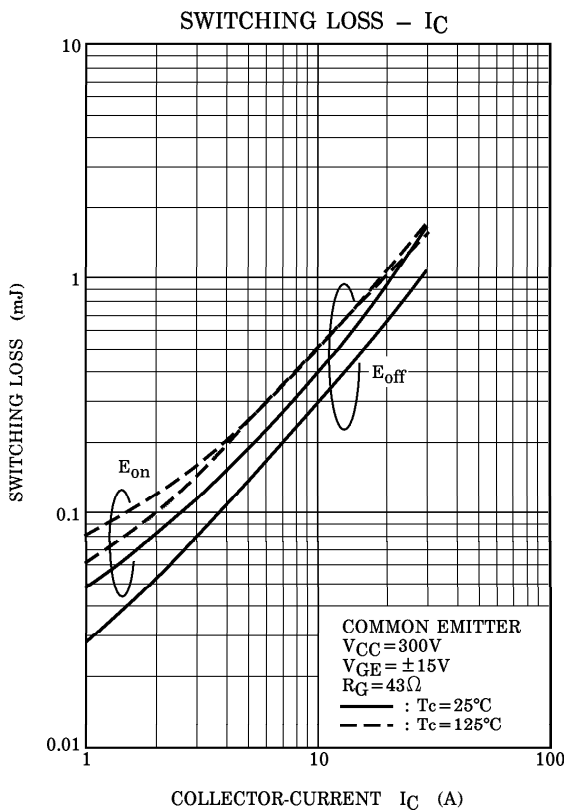
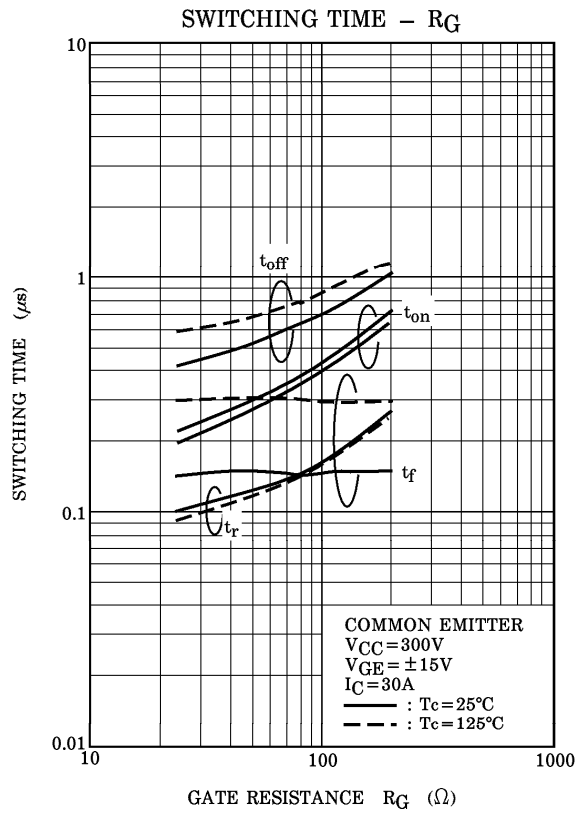
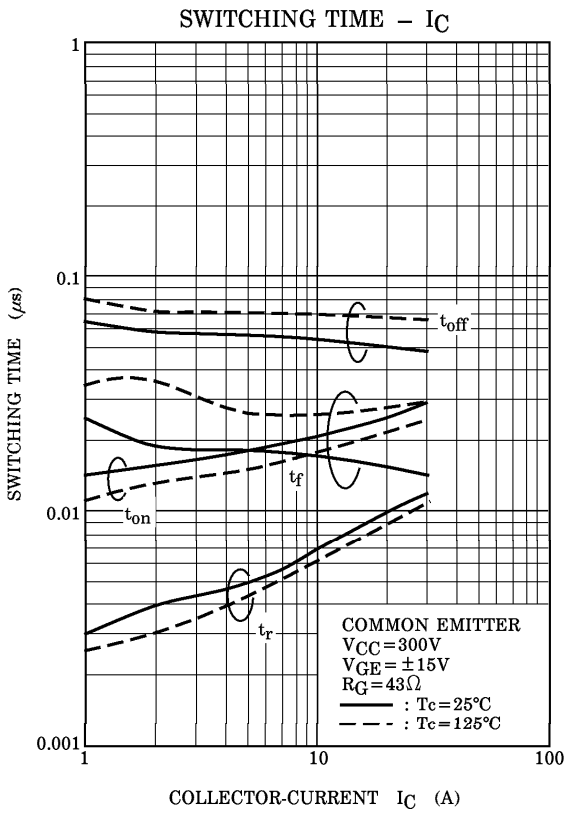
CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Zero-power Resistance		R_{25}	$I_{TM} = 0.2mA, T_c = 25^{\circ}C$	17.31	20	23.14	$k\Omega$
B Value		$B_{25/85}$	$T_c = 25^{\circ}C / T_c = 85^{\circ}C$	—	3760	—	K

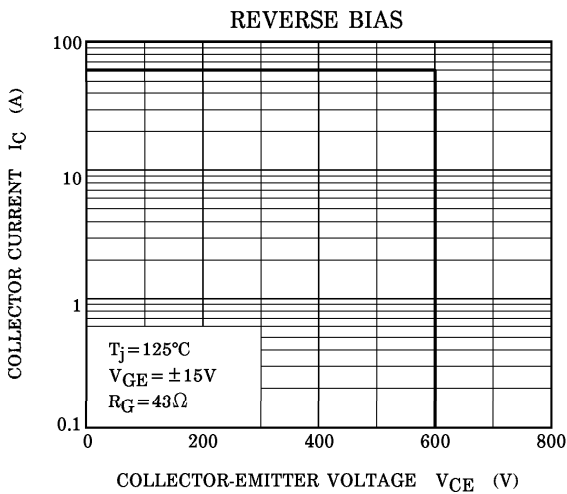
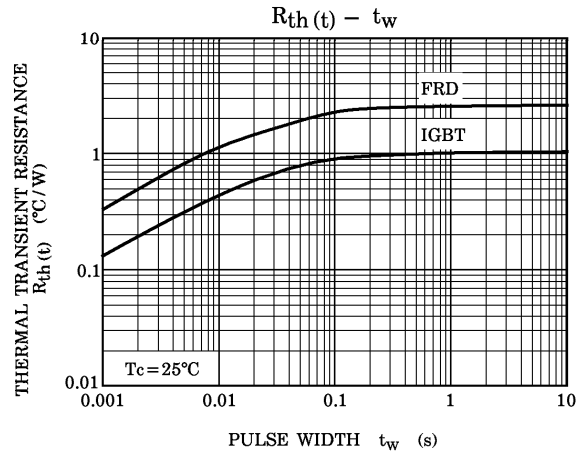
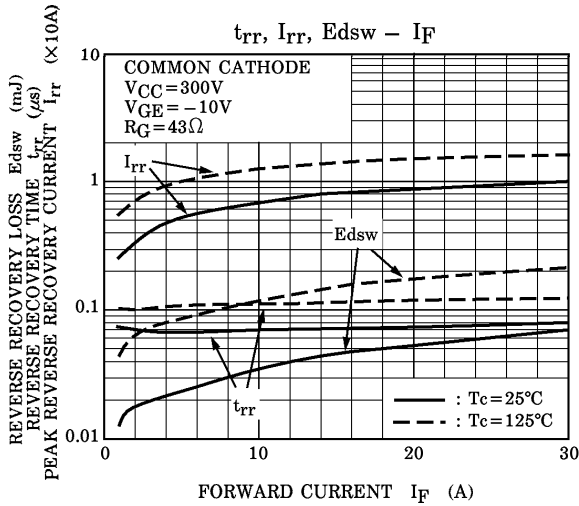
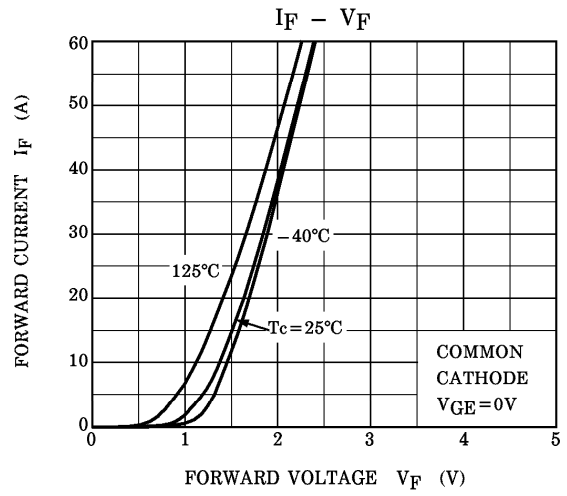
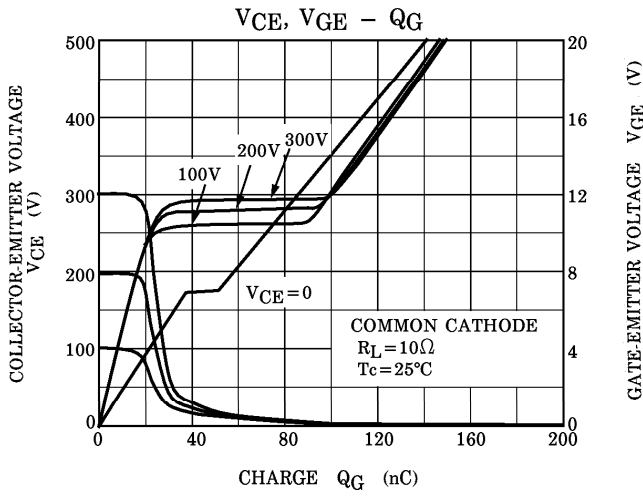
(Note 1) Switching Time Test Circuit & Timing Chart



a. Inverter stage







b. Converter stage

